Extracting the phase information from atomic memory by intensity correlation measurement

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Abstract: We demonstrate experimentally controlled storage and retrieval of the optical phase information in a higher-order interference scheme based on Raman process in $^{87}$Rb atomic vapor cells. An interference pattern is observed in intensity correlation measurement between the write Stokes field and the delayed read Stokes field as the phase of the Raman write field is scanned. This result implies that the phase information of the Raman write field can be written into the atomic spin wave via Raman process in a high gain regime and subsequently read out via a spin-wave enhanced Raman process, thus achieving optical storage of phase information. This technique should find applications in optical phase image storage, holography and information processing.

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References and links

1. Introduction

Over the past decade, researchers have developed numerous techniques to control the interaction between matters and light, such as stimulated Raman adiabatic process (STIRAP) [1], coherent population oscillation (CPO) [2, 3], electromagnetically induced transparency (EIT) [4] and Raman process [5]. One of the goals is to achieve quantum memory and quantum storage of light in matters. Among these, electromagnetically induced transparency (EIT) and Raman processes are some of the popular approaches and have been applied widely in holography, optical imaging [6, 7], remote sensing, and information processing [8–10]. More recently, stimulated Raman processes are employed to achieve broad band quantum storage in atomic ensembles [11–13]. Although these schemes stored complete information of a quantum state of light, sometimes only partial information is needed for storage in some applications. For example, some traditional optical communications [14, 15] only need amplitude information. Furthermore, these schemes generally require two optical fields that satisfy the two-photon resonance condition, leading to an increased degree of complexity.

On the other hand, phase is known as one of the basic quantities related to the coherence property of an optical field. The controlled storage and retrieval of the phase information is essential to many coherent processes such as image storage [16] and gradient echo memory [17], which are related to coherent transfer between light and atomic coherence. Spontaneous Raman process only involves the injected pump laser and is simpler compared to the stimulated Raman process. But the phases of the Stokes fields generated in spontaneous process are random from...
one shot to the next [18–20], which prevents us from using the traditional first-order interference method to write and retrieve the phase information. Fortunately, in spontaneous Raman scattering, besides the Stokes field, another field known as the atomic spin wave is also generated simultaneously and there exists a phase anti-correlation between the generated Stokes field and the atomic spin wave [20]. In this paper, we will utilize this phase correlation to observe an interference fringe in intensity correlation measurement that leads to a simple protocol for controlled phase memory and its retrieval using spontaneous Raman process in $^{87}$Rb atomic vapor cells.

2. Theory

Figure 1 shows the schematic diagram of the storage and retrieval processes as well as the energy levels of the $^{87}$Rb atoms. The general scheme is similar to that in [20]. The difference lies in the measurement process: we use a second-order intensity correlation method to retrieve the phase information stored in atomic ensemble. Since phase is a relative quantity, we need a second Raman process, denoted by subscript label "2", as a reference. Phase information can be extracted by mixing relevant fields of the two processes. In the protocol shown in Fig. 1, we first write a certain phase (denoted as the memory phase $\theta_m$ in Fig. 1(a)) into the atomic ensemble by Raman scattering with $W_1$ field, and then read out by a method of enhanced Raman scattering [21, 22] with $R_1$ field. As is well-known, the Raman scattering in $^{87}$Rb atoms with a $\Lambda$-shaped energy level is a three-wave mixing process involving a write field $W$, a Stokes field $S$ and a collective atomic spin wave $a$ as shown in Fig. 1(b). In the write process, taking $W_1$
field for example, the Stokes field starts from the spontaneous emission with an arbitrary phase $\varphi_{SW1}$. Subsequently it is amplified by the stimulated process and the phase $\varphi_{SW1}$ is preserved. The phase $\varphi_{a1}$ of the atomic spin wave is correlated to the phase $\varphi_{SW1}$ of the Stokes field with the relation of $\varphi_{a1} = (\varphi_{W1} + \theta_m) - \varphi_{SW1}$ [20]. So the Raman scattering of $W_1$ field can be regarded as the write process: writing the memory phase $\theta_m$ into the atomic spin wave $a_1$. After the writing process, a read field $R$ is sent into the atomic ensemble. This process is the enhanced Raman scattering [21, 22], taking $R_1$ field for example, the Stokes field $S_{R1}$ starts from the stimulated emission with the pre-built atomic spin wave $a_1$ as the seed, the corresponding phase relation is $\varphi_{SR1} = \varphi_{R1} - \varphi_{a1}$. So the Raman scattering of $R_1$ field can be regarded as the read process: reading out the phase information from the previously built atomic spin wave $a_1$ into $SR_1$ field with $\varphi_{SR1} = \varphi_{R1} - \varphi_{W1} + \varphi_{SW1} - \theta_m$. However, due to the random characteristic of the phases $\varphi_{SW1}$, we cannot use the first-order interference to retrieve the phase information. On the other hand, second-order intensity correlation measurement between the write Stokes $S_W$ and the read Stokes $S_R$ fields can remove the effect of the random phase $\varphi_{SW}$. Let us demonstrate next with a simple theory how this can be achieved.

![Diagram](https://example.com/diagram.png)

Fig. 2. (a) Experimental setup. AOM: acousto-optic modulator; PZT: piezoelectric transducer; SMF: single mode fiber; PBS: Polarization beam splitter; BS: beam splitter. AT: attenuator. (b) the time sequence, the duration of the OP field is 80$\mu$s.

From [19], we learn that the intensities of the output fields $S_W, S_R$ after mixing have the form of

$$I_{SW}(t) = A(t)[1 + v_W \cos(\Delta \Omega_W t + \Delta \varphi_{SW})],$$

(1)
Because $v_W$ with $\zeta$ are close in intensity. The intensity correlation function can then be written as \[23\]

information.

So we have

\[g \approx \frac{2}{T} \int dt \Delta \Omega t \approx \frac{1}{T} \int dt A(t) B(t') [1 + v_w \cos(\Delta \Omega t + \Delta \phi_{SW})] \times [1 + v_r \cos(\Delta \Omega t' + \Delta \phi_{SR})]. \tag{3}\]

Usually, the beat signal is much faster than the pulse width so that we can approximately pull the slowly varying $A(t)B(t')$ out of the integral:

$$G(2) \approx \langle A(t)B(t') \rangle_T \frac{dt}{T} [1 + v_w \cos(\Delta \Omega t + \Delta \phi_{SW})] \times [1 + v_r \cos(\Delta \Omega t' + \Delta \phi_{SR})]. \tag{4}$$

Since $\Delta \Omega_w \approx \Delta \Omega_r$, we set $T \approx 2\pi n / \Delta \Omega_w \approx 2\pi n / \Delta \Omega_r \approx 4\pi n / (\Delta \Omega_w + \Delta \Omega_r) (n \text{ integer})$. After the expansion, the fast oscillating terms will be averaged to approximately zero and Eq. (4) becomes

$$G(2) \approx \langle A(t)B(t') \rangle_T [1 + \frac{2}{v_w} v_r \gamma \cos(\Delta \phi_{SW} - \Delta \phi_{SR})], \tag{5}$$

with $\gamma \approx \sin \beta / \beta \equiv (\Delta \Omega_w - \Delta \Omega_r) T / 2 \approx 0$ due to $\Delta \Omega_w \approx \Delta \Omega_r$.

To eliminate the fluctuations in $A, B$, we evaluate the normalized intensity correlation function

$$g(2) \equiv G(2) / \langle I_{SW} \rangle_T \langle I_{SR} \rangle_T \tag{6}$$

with $\langle I_{SW} \rangle_T = (1/T) \int_T dt I_{SW}(t) \approx \int_T dt A(t) B(t')$ and $\langle I_{SR} \rangle_T = (1/T) \int_T dt I_{SR}(t') \approx \int_T dt B(t') / T$.

So we have

$$g(2) = g_0(2) [1 + \frac{1}{2} v_w v_r \gamma \cos(\Delta \phi_{SW} - \Delta \phi_{SR} + \theta_m)], \tag{7}$$

where $g_0(2) \equiv \langle A(t)B(t') \rangle_T / \langle A(t) \rangle_T \langle B(t') \rangle_T$, which is the normalized intensity correlation function of the two Stokes fields. Since $W_1$ and $W_2$ are derived from a common source, $\Delta \phi_{SW}$ is definite and so is $\Delta \phi_{SR}$. Note that the random phase $\Delta \phi_{SR}$ is cancelled out in Eq. (7). So, we can recover $\theta_m$ from the intensity correlation function $g(2)$, thus realize the readout of the phase information.

From Eq. (7), we see that the visibility of the fringes in $g(2)$ is

$$V = \frac{1}{2} v_w v_r \gamma. \tag{8}$$

Because $v_w, v_r, \gamma$ are limited by 1, the ideal value of visibility is 50% when $v_w, v_r, \gamma \sim 1$.

If we consider the decoherence of atomic spin wave \[19\], the normalized intensity correlation function is

$$g(2) = g_0(2) [1 + V e^{-\xi T} \cos(\Delta \phi_w - \Delta \phi_S + \theta_m)], \tag{9}$$

with $\xi$ as the decay constant.
3. Experiment setup and result

The experimental setup is shown in the Fig. 2. Pure $^{87}$Rb atoms are contained in a 75mm long glass cell. The cell is placed inside a four-layer $\mu$-magnetic shielding to reduce stray magnetic fields and is heated up to 75$^\circ$C using a bifilar resistive heater. The write laser $W$ and the read laser $R$, detuned from the $^{87}$Rb D1 line ($S^2S_{1/2}, F = 1 \rightarrow S^2P_{1/2}, F' = 2$ transition) by $\Delta W = 0.8$GHz and $\Delta R = 1$GHz respectively, are from two different single-frequency diode lasers operating at 795 nm. The detunings of the write and read are chosen for the optimum overall Raman efficiency: a trade-off between larger Raman interaction and less absorption.

$W_1$ and $W_2$ fields, which are split from $W$, co-propagate in parallel through the atomic cell. $R_1$ and $R_2$ beams, split from $R$ laser, counter-propagates and overlaps with $W_1$ and $W_2$ fields, respectively. The waist of $W_1$, $W_2$, $R_1$ and $R_2$ fields are 0.25mm, 0.28mm, 0.30mm and 0.34mm, respectively. The power of the $W_1$, $W_2$, $R_1$ and $R_2$ are 0.76 mW, 0.98 mW, 0.19 mW and 0.20 mW, respectively. A piezo-electric transducer (PZT) is placed in $W_1$ route to modulate the phase of the $W_1$ field. Then we can define this modulation as the memory phase $\theta_m$. All atoms are initially prepared in the ground state $|g\rangle$ by optical pumping (OP). After optical pumping, $W$ and $R$ fields are turned on in a sequence as shown in Fig. 2(b). The write and read fields are chopped into pulses and controlled by acoustic optic modulators (AOM), and the durations of the write and read pulses $T_W$ and $T_R$ are both equal to 1.2$\mu$s. The Stokes fields $S_{W1}$, $S_{W2}$, $S_{R1}$ and $S_{R2}$ are produced from $W_1$, $W_2$, $R_1$ and $R_2$ fields, respectively. The $S_W$ field is the combined field of the $S_{W1}$ and $S_{W2}$ and the $S_R$ field is the combined field of $S_{R1}$ and $S_{R2}$. Since the polarization of the Stokes fields are orthogonal to the corresponding pump lasers, we can separate them with polarization beam splitters (PBS). $S_W$ and $S_R$ fields are coupled into single-mode fibers (SMF) for spatial mode clean-up and detected by photo-detectors $D_1$ and $D_2$ and recorded by an oscilloscope.

![Temporal behavior of SW and SR fields](image.png)

Fig. 3. Temporal behavior of $S_W$ and $S_R$ fields. $\tau$ is 0.1 $\mu$s. The red line and blue line are the $S_W$ and $S_R$ fields generated in one write-read pulse period. The black dashed curve and green dashed curve are the averaged intensities over 100 pulses of the $S_W$ and $S_R$ fields.
As already observed in [20], the temporal behaviors of $S_W$ and $S_R$ fields for single pulse (solid line) and 100 pulse-average are shown in Fig. 3. Because of the different AC Stark shifts caused by uneven pumping from $W_1$ and $W_2$ fields and from $R_1$ and $R_2$ fields, both $S_W$ and $S_R$ exhibit beat signals [19]. As seen from Fig. 3, the visibilities $v_{W}, v_{R}$ of the beat signals are almost 100% and the beat periods of $S_W$ and $S_R$ are 0.55$\mu$s and 0.59$\mu$s, respectively. The corresponding beating frequencies are 1.82$MHz$ and 1.69$MHz$. These values are adjusted to be the same by the relative intensities of $W_1, W_2, R_1, R_2$ so that $\beta \ll 1$ and $\gamma \sim 1$ in Eq. (8). The disappearance of the beat signal in multi-pulse average is due to the randomness of $\Delta \phi_{SW}, \Delta \phi_{SR}$.

![Memory phase $\theta_m$](image)

**Fig. 4.** A sample of $g^{(2)}$ as a function of storage phase $\theta_m$ at $\tau = 0.1\mu$s. $\theta_m$ is the modulated phase on $W_1$, tuned by PZT. The square is the experimental data and the red line is a fit curve to sine-function.

Experimentally, $g^{(2)}$ value is calculated by placing the recorded $I_{SW}(t)$ and $I_{SR}(t+T+\tau)$ in Eq. (6). The integration time $T$ is the pulse duration of $T_W = T_R = 1.2\mu s \approx 4\pi/\Delta \Omega_R$. Thus for one record of $S_W$ and $S_R$ shown in Fig. 3, we can obtain one value of $g^{(2)}$. It takes about 100$\mu$s for one measurement. When the phase $\theta_m$ is modulated slowly by the PZT, a series of pulses of $I_{SW}(t)$ and $I_{SR}(t')$ are measured and the corresponding $g^{(2)}$ values can be obtained as described above.

Figure 4 shows the result of one such scan of the phase $\theta_m$. We plot $g^{(2)}$ values as a function of the phase $\theta_m$. They show an interference pattern with a sine-function fitting to the phase $\theta_m$, which agreed with theoretical prediction given from Eq. (7). There is a phase shift of $\pi/2$ compared with cosine function because of the initial phase ($\Delta \phi_w - \Delta \phi_r$) in Eq. (7). The best visibility of the interference fringe in Fig. 4 is 43% when the delay time $\tau$ between the write and read laser pulses is equal to 0.1$\mu$s. This value is smaller than the best theoretical value of 50%. This is due to the slight mismatch between $\Delta \Omega_w$ and $\Delta \Omega_r$, which makes $\gamma < 1$ in Eq. (8). Another consequence of $\Delta \Omega_w \neq \Delta \Omega_r$ is the non-vanishing of the fast oscillating terms in Eq. (4). Since these terms depend on the random phases of $\Delta \phi_{SW}$ and $\Delta \phi_{SR}$, the effect is a small

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fluctuation in $g^{(2)}$ and its average leads to the reduction of the visibility. A quick estimation based on experimental parameters gives about 5% reduction.

![Graph showing interference visibility as a function of delay time between the write and read pulses.]

To demonstrate the effect of decoherence of the atomic spin waves on the storage time, we plot in Fig. 3 the visibilities of the interference pattern as a function of the delay times $\tau$. As can be seen, the visibilities drop as the delay times increase and the decay time in Fig. 5 is $2\mu s$. This is mainly due to the coherent atoms flying out of the region of the read beam, but not the atomic collisions. The dephasing time due to atomic collisions is about several milliseconds under our experimental conditions. The transit time can be calculated by $\tau = r/v_a$, here $r$ is the waist of read field and $v_a$ is the atom’s average speed of $300 \sim 400 m/s$ at $75^\circ C$. So $\tau \sim 1\mu s$ in our experiment, it is close to the decay time in Fig. 5.

4. Conclusion

In conclusion, we realized the phase memory experimentally. The memory phase carried by the pump laser is first written into the atomic system by normal Raman process, and then read out by an enhanced Raman process, and finally extracted through second-order intensity correlation measurement between the write and read Stokes signals at two separate paths.

This kind of phase memory technology using spontaneous Raman scattering can be applied in the fields related to the encrypted storage of the optical phase [24]. The randomness in the phase of the spontaneous Raman scattering can be used in the encryption and memory processes. The encrypted information, i.e., the phase of write Stokes field is generated from non-deterministic behavior of atomic system [25]. The intensity correlation measurement can be considered as decryption process. In the experiment, where we use $^{87}$Rb atomic vapor to demonstrate our protocol, the bandwidth and memory time are limited by the initial preparation and decoherence time of our atomic system. In future possible practical applications, some other materials are preferred. For example, diamond can provide larger bandwidth of the phase memory [26], and rare-earth-ion-doped crystal can provide longer memory time [27].

Our protocol is somewhat similar to holography in that both require the interference. But the difference is that holography is based on the first-order interference so that the optical loss of the reference and illumination lasers will decrease the image quality. On the other hand, our protocol is the combination of the first-order and second-order interference and the quality is...
independent of the loss of the lasers.

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